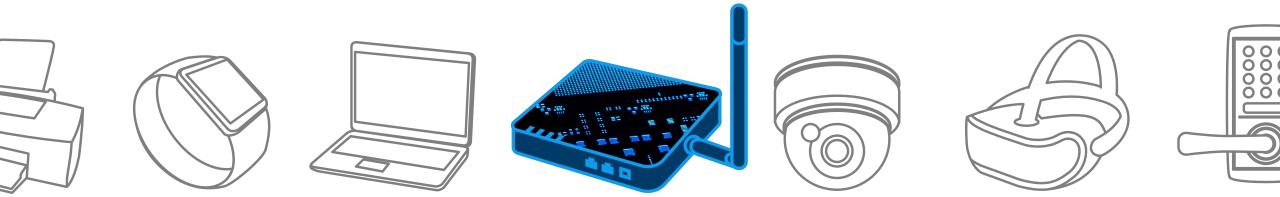


IoT Sensor

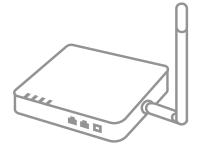
Solution Proposal by Toshiba



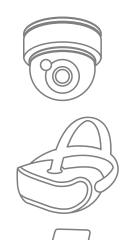
R21



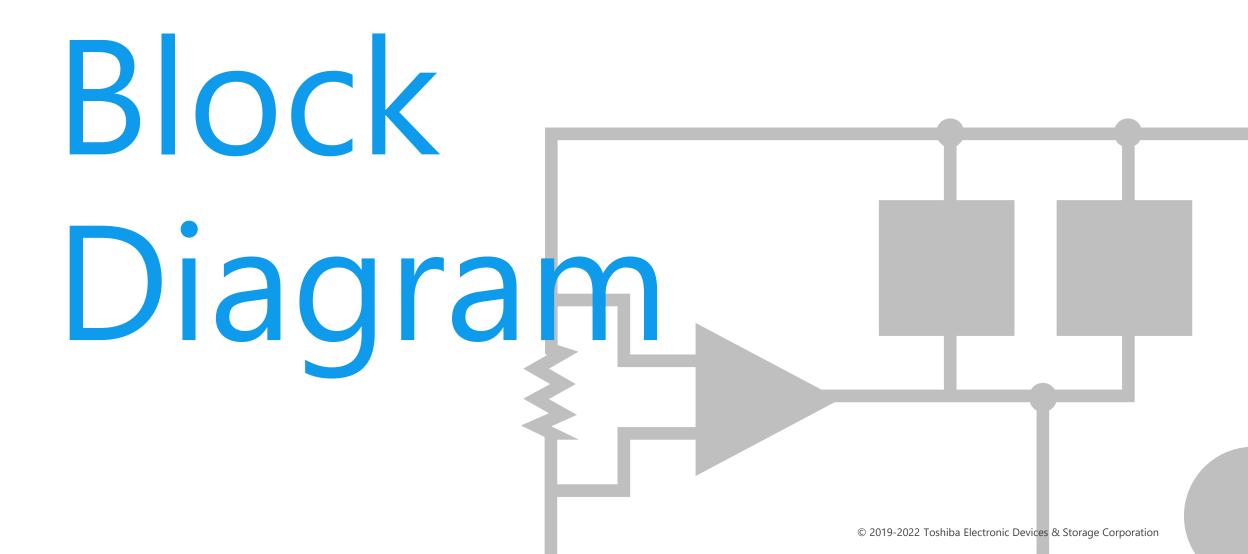




Toshiba Electronic Devices & Storage Corporation provides comprehensive device solutions to customers developing new products by applying its thorough understanding of the systems acquired through the analysis of basic product designs.

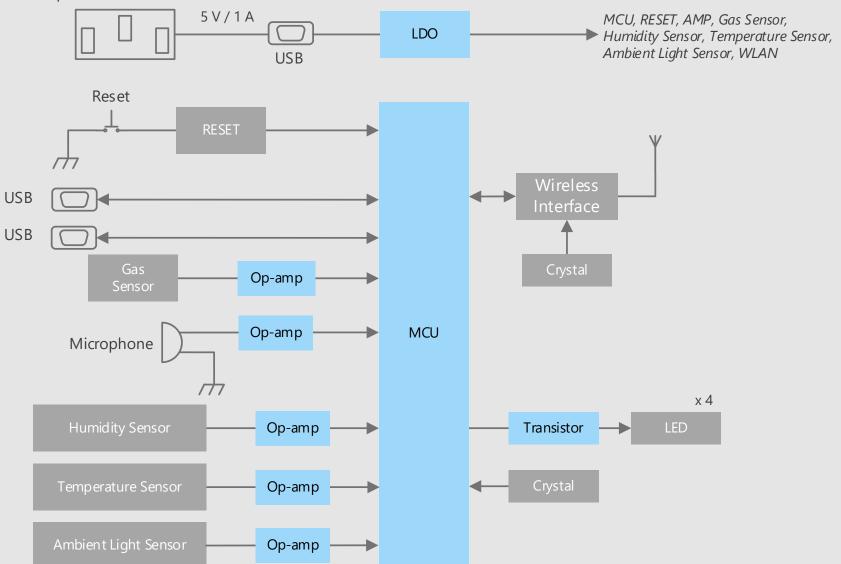


© 2019-2022 Toshiba Electronic Devices & Storage Corporation

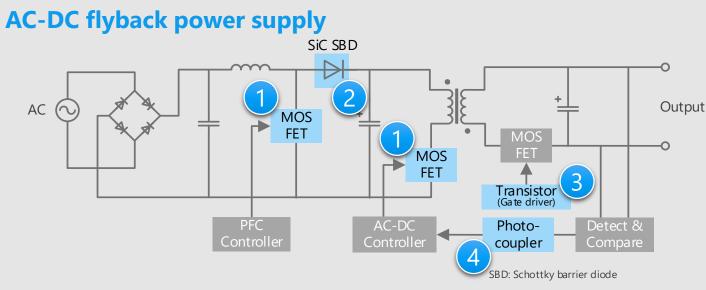


IoT Sensor Overall block diagram

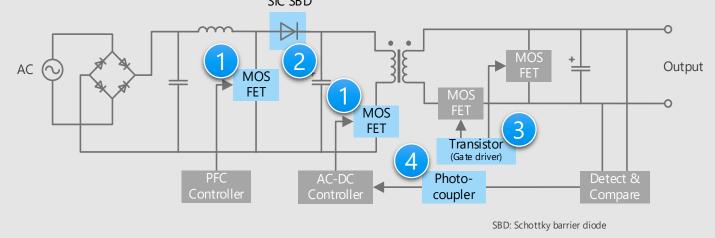
AC Adapter



IoT Sensor Detail of power supply unit



AC-DC forward power supply



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

- High voltage MOSFETs are suitable for primary side of AC-DC converters.
- SiC type Schottky barrier diodes are suitable for PFC circuits.

Proposals from Toshiba

- Suitable for high efficiency power supply switching MOSFET
- High current surge resistance and low switching loss

SiC Schottky barrier diode

- Suitable for high speed gate driving of MOSFET

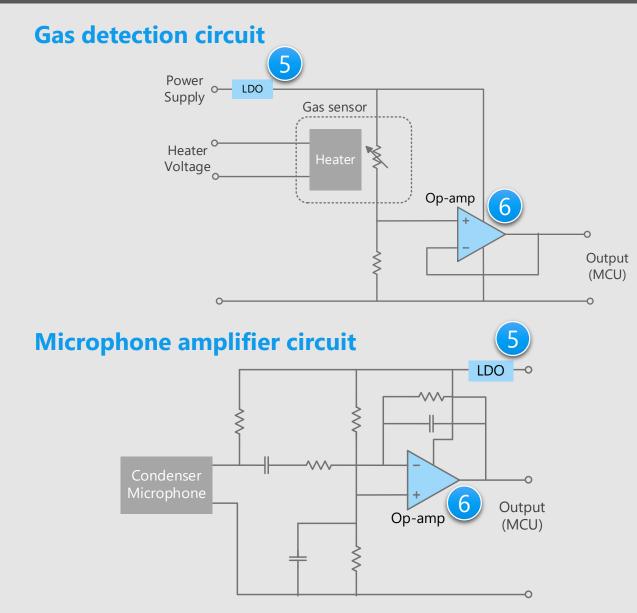
Bipolar transistor (Gate driver)

Suitable for power supply feedback circuit

IC output photocoupler

3

IoT Sensor Detail of sensor units



Criteria for device selection

- PSRR (Power Supply Rejection Ratio) of LDO regulator is an important parameter for sensor circuits.
- The operational amplifier should be low current consumption or low noise device.
- Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

Supply the power with low noise Small surface mount LDO regulator



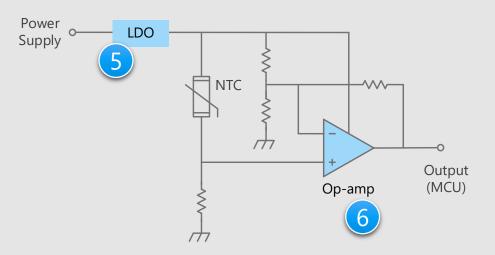
- Amplification of detected very small signals

Low current consumption op-amp / Low noise op-amp

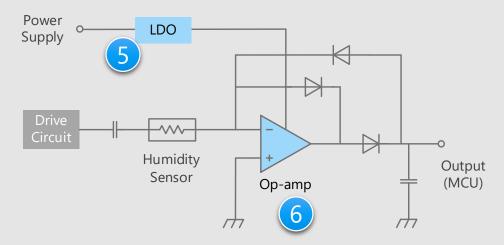


IoT Sensor Detail of sensor units

Temperature detection circuit



Humidity detection circuit



Criteria for device selection

- PSRR (Power Supply Rejection Ratio) of LDO regulator is an important parameter for sensor circuits.
- The operational amplifier should be low current consumption or low noise device.
- Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

Supply the power with low noise Small surface mount LDO regulator



6

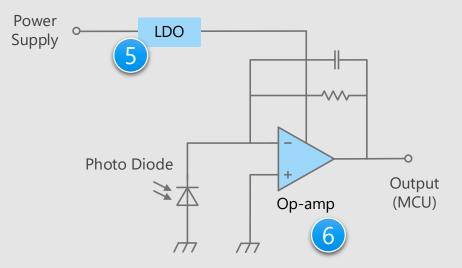
- Amplification of detected very small signals

Low current consumption op-amp / Low noise op-amp



IoT Sensor Detail of sensor unit

Ambient light detection circuit



Criteria for device selection

- PSRR (Power Supply Rejection Ratio) of
 LDO regulator is an important parameter
 for sensor circuits.
- The operational amplifier should be low current consumption or low noise device.
- Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

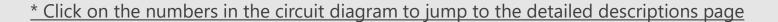
Supply the power with low noise Small surface mount LDO regulator



6

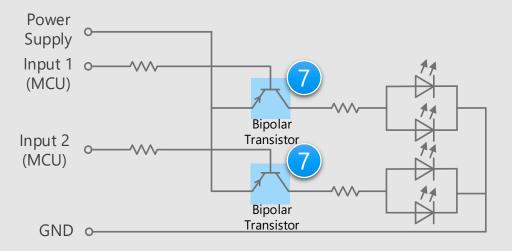
- Amplification of detected very small signals

Low current consumption op-amp / Low noise op-amp



IoT Sensor Detail of LED drive unit

LED drive circuit



Criteria for device selection

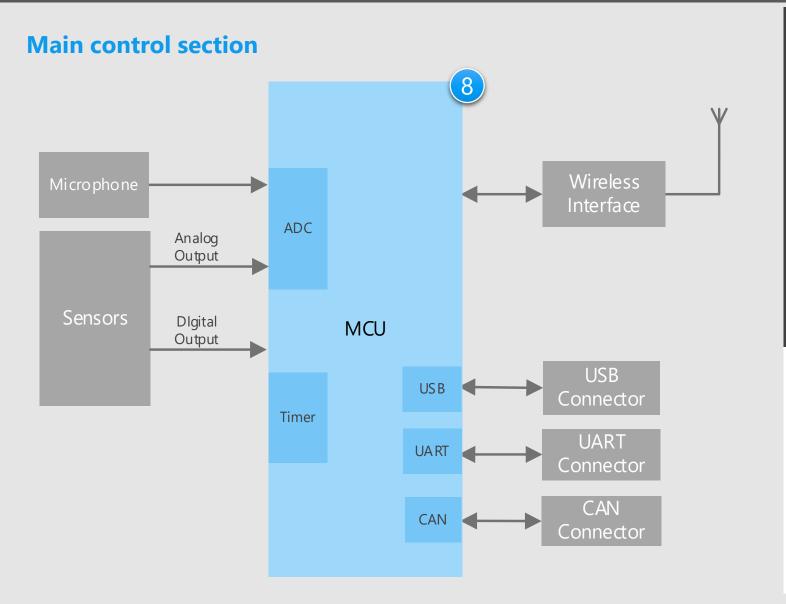
Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

 Small package products with high breakdown voltage and high h_{FE} Bipolar transistor

* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

IoT Sensor Detail of main control unit



Criteria for device selection

- Multi-channel analog or digital interfaces are needed for monitoring various sensor output.
- High performance of data processing is required to analyze sensor data at realtime.
- The communication channel is required to upload sensor data and analysis results to the cloud.

Proposals from Toshiba

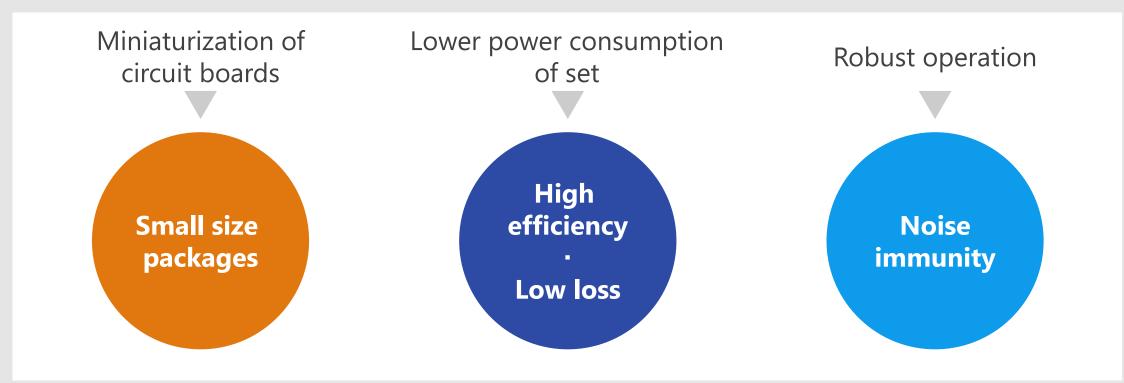
 High processing performance MCU supports multi-channel sensor interfaces and various communication standards

MCU M360 / M4N Group

Recommended Devices

Device Solutions to address customer needs

As described above, in the design of IoT sensor, "Miniaturization of circuit boards", "Low power consumption of set" and "Robust operation" are important factors. Toshiba's proposals are based on these three solution perspectives.



Device Solutions to address customer needs







Suitable for switching regulators and easy to handle and contributes to miniaturization.

Low on-resistance

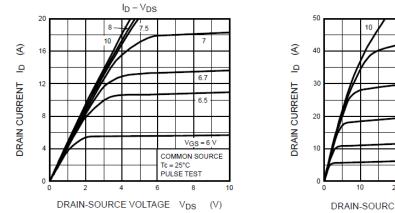
By keeping the on-resistance between the drain and source low, heat generation and power consumption can be also kept low.

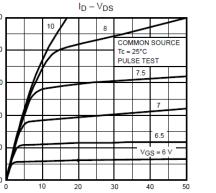


Low leakage current

Drain leakage current $I_{DSS} = 10 \ \mu A \ (Max) \ (@V_{DS} = 500 \ V)$

TK18A50D Characteristics Curves





DRAIN-SOURCE VOLTAGE VDS (V)

Lineup

Part number	TK18A50D	TK12P50W	
Package	TO-220SIS	DРАК 🔷	
V _{DSS} (Max) [V]	500	500	
I _D (Max) [A]	18	11.5	
P _D (Max) [W]	50	100	
C _{iss} (Typ.) [pF]	2600	890	
R _{DS(ON)} (Max) [Ω]	0.27	0.34	
Polarity	N-ch	N-ch	



TO-220-2L

High Small size Noise efficiency packages immunity Low loss

Value provided

TO-220F-2L

(Isolation type)

Contribute to higher efficiency and miniaturization of power supply.

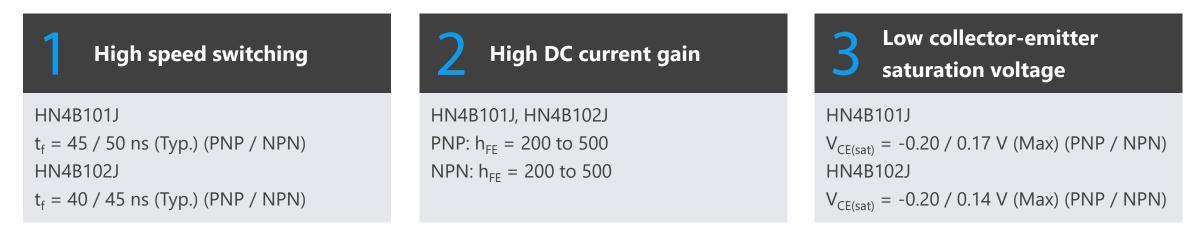
Low leakage current Low forward voltage **High surge current resistance** The non-repetitive peak forward surge current : V_{F} (Typ.) = 1.45 V [Note] I_{P} (Max) = 20 μ A [Note] I_{FSM} = 37 A / 39 A [Note] By using the improved JBS structure, low leakage By using the improved JBS structure, low forward By using the improved JBS (Junction Barrier voltage at high current is realized. controlled Schottky) structure incorporating the current is realized. concept of the Merged PiN Schottky (MPS) structure, high surge current resistance is realized. Internal Circuit Lineup Heatsink TRS4A65F TRS4E65F Part number TO-220F-2L TO-220-2L Package 1: Cathode V_{RRM} [V] 650 650 2: Anode 4 I_{F(DC)} [A] 4 I_{ESM} [A] 37 39 I_R (Typ. / Max) [μA] 0.2 / 20 0.2 / 20 V_{F} (Typ.) [V] @I_F = 4 A 1.45 1.45 2 2 [Note] TRS4A65F / TRS4E65F product data



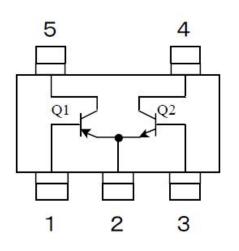
Small size packages . Low loss

Value provided

Bipolar transistor suitable for MOSFET gate driving.



HN4B101J / HN4B102J Circuit configuration



Lineup		
Part number	HN4B101J	HN4B102J
Package	SMV	SMV
V _{CEO} [V] @Q1 / Q2	-30 / 30	-30 / 30
I _c [A] @Q1 / Q2	-1.0 / 1.2	-1.8 / 2
h _{FE} (Min / Max)	200 / 500	200 / 500
Polarity	Q1:PNP + Q2:NPN	Q1:PNP + Q2:NPN





This photocoupler combines an infrared light emitting diode with high optical output power and a light receiving IC chip with high gain and high speed.

Analog output

The output current changes in an analog manner according to the input LED current. It is suitable for power supply feedback circuits. Common mode transient immunity 15 kV/μs (TLP2309)

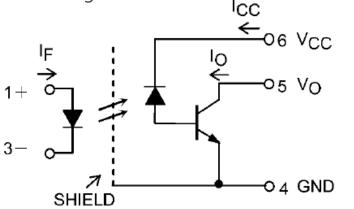
For applications where high dV/dt is applied to both ends of the photocoupler, high CMTI ^[Note] is required. Our device realizes the CMTI of 15 kV/µs (Min) by adapting shield between the input and output. (TLP2309) [Note] Common Mode Transient Immunity



High speed

Propagation delay time is 1 μ s (Max) in operation temperature range. The design is easier than when using our transistor output photocoupler. (TLP2309)

Internal circuit configuration



Lineup				
Part number	TLP2309	TLP2719(LF4)		
Package	5pin SO6	SO6L(LF4)		
BV _s [Vrms]	3750	5000		
NRZ (Typ.) [Mbps]	1	1		
CM _H , CM _L (Min) [kV/μs]	±15	±10		



Wide lineup from general purpose type to small package type are provided. Contribute to realize a stable power supply not affected by fluctuation of battery.

Low dropout voltage

The originally developed latest process significantly improved the dropout voltage characteristics.



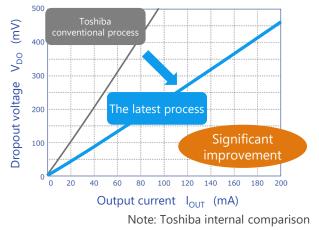
Many product series that realize both high PSRR (Power Supply Rejection Ratio) and low output noise voltage characteristics are provided. They are suitable for stable power supply for analog circuit.



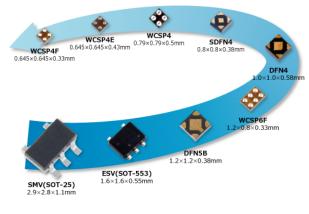
Low current consumption

0.34 μ A of I_{B(ON)} is realized by utilizing CMOS process and unique circuit technology. (TCR3U Series)





Rich package lineup



Part number	TCR15AG Series	TCR13AG Series	TCR8BM Series	TCR5BM Series	TCR5RG Series	TCR3RM Series	TCR3U Series	TCR2L Series	TAR5 Series
Features	Low dropout voltage High PSRR		High PSRR Low noise Low current consumption		Low current consumption		15 V Input voltage Bipolar type		
I _{OUT} (Max) [A]	1.5	1.3	0.8	0.	.5	0.	3		0.2
PSRR (Typ.) [dB] @f = 1 kHz	95	90	98	98	100	100	70	-	70
Ι _в (Тур.) [μΑ]	25	56	20	19	7	7	0.34	1	170



Low current consumption type and low noise type operational amplifiers maximize the performance of system.

Low voltage operation

We have a lineup of low power supply voltage-driven operational amplifiers using CMOS process for low power supply voltage-driven IoT equipment.

Low current consumption (TC75S102F) I_{DD} = 0.27 μA (Typ.)

CMOS processes have been used to achieve lower current consumption. This contributes to lower power consumption and longer life of IoT equipment.



Low noise (TC75S67TU)

V_{NI} = 6.0 nV/√Hz (Typ.) @f =1 kHz

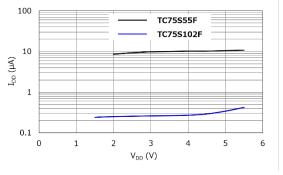
This CMOS operational amplifier can amplify minute signals detected by various sensors ^[Note] with very low noises. By optimizing the process, the equivalent input noise voltage has been reduced.

[Note] Sensor types: vibration, shock, acceleration, pressure, infrared, temperature, etc.

TC75S102F

Current Consumption Characteristic (Toshiba internal comparison)

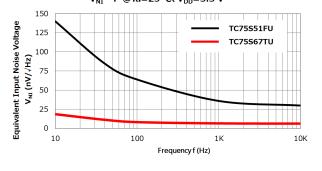
Low current consumption product TC75S102F



TC75S67TU

Noise Characteristic (Toshiba internal comparison)



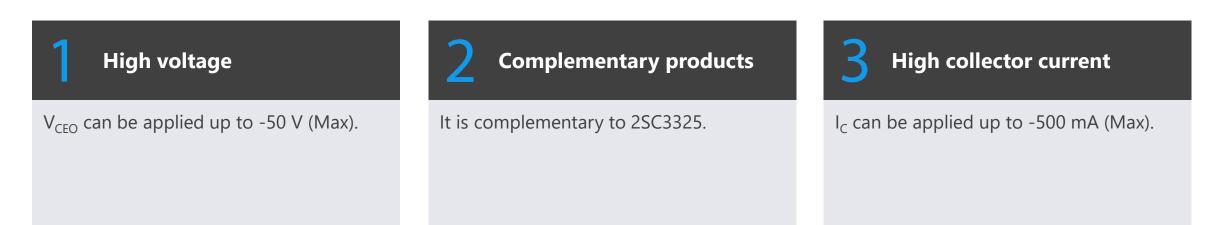


	Lineup						
	Part number	TC75S102F	TC75S67TU				
s	Package	SMV	UFV 🔶				
	V _{DD} - V _{SS} [V]	1.5 to 5.5	2.2 to 5.5				
	V _{IO} (Max) [mV]	1.3	3				
	CMV _{IN} (Max) [V]	V _{DD}	1.4 (@V _{DD} = 2.5 V)				
	I _{DD} (Typ. / Max) [μA]	0.27 / 0.46 (@V _{DD} = 1.5 V)	430 / 700 (@V _{DD} = 2.5 V)				
	V _{NI} (Typ.) [nV/√Hz] @f = 1 kHz	-	6				

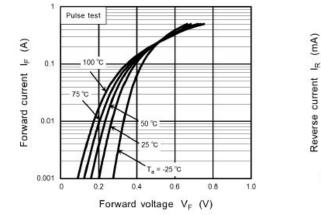


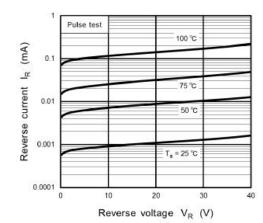


With wide product lineup, Toshiba provides products that meet the needs of customers.



2SA1313 Characteristics





Lineup

Part number	2SA1313
Package	S-Mini
V _{CEO} [V]	-50
I _c [mA]	-500
P _c [mW]	200
Polarity	PNP



High Noise Small size efficiency packages mmunity Low loss

Value provided

Monitoring sensor at low power consumption by using built-in AD converters, timers and various communication interfaces.

Built-in Arm[®] Cortex[®]-M3/M4 CPU core

The product lineup is equipped with Arm Cortex-M3/M4 cores. It is suitable for processing sensor data at real time. Various development tool and their partners allow users many options.



System cost down and development efficiency improvement

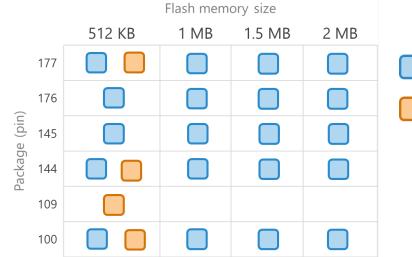
These devices executes sensing data monitoring and processing efficiently by combining built-in multi-channel AD converters and timers. In addition, M4N Group products have a lineup of 20 products to provide suitable products for the set.



Various communication

interfaces

These devices supports major communication interfaces such as USB, CAN, UART, FUART, SPI, I²C and external bus. User can construct a communication system easily with a cloud.



\square	M4N	Group

	M360	Group
--	------	-------

Lineup				
Family	Group	Function		
TX Family	M360 Group	Arm [®] Cortex [®] -M3, Max. 80 MHz operation frequency. M368 / M369 products.		
TXZ+™ Family	M4N Group	Arm [®] Cortex [®] -M4, Max. 200 MHz operation frequency.		

If you are interested in these products and have questions or comments about any of them, please do not hesitate to contact us below:

Contact address: https://toshiba.semicon-storage.com/ap-en/contact.html

Terms of use

This terms of use is made between Toshiba Electronic Devices and Storage Corporation ("We") and customers who use documents and data that are consulted to design electronics applications on which our semiconductor devices are mounted ("this Reference Design"). Customers shall comply with this terms of use. Please note that it is assumed that customers agree to any and all this terms of use if customers download this Reference Design. We may, at its sole and exclusive discretion, change, alter, modify, add, and/or remove any part of this terms of use at any time without any prior notice. We may terminate this terms of use at any time and for any reason. Upon termination of this terms of use, customers shall destroy this Reference Design. In the event of any breach thereof by customers, customers, shall destroy this Reference Design, and furnish us a written confirmation to prove such destruction.

1. Restrictions on usage

1. This Reference Design is provided solely as reference data for designing electronics applications. Customers shall not use this Reference Design for any other purpose, including without limitation, verification of reliability.

2. This Reference Design is for customer's own use and not for sale, lease or other transfer.

3.Customers shall not use this Reference Design for evaluation in high or low temperature, high humidity, or high electromagnetic environments.

4. This Reference Design shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.

2. Limitations

1.We reserve the right to make changes to this Reference Design without notice.

2. This Reference Design should be treated as a reference only. We are not responsible for any incorrect or incomplete data and information.

- 3.Semiconductor devices can malfunction or fail. When designing electronics applications by referring to this Reference Design, customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of semiconductor devices could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Customers must also refer to and comply with the latest versions of all relevant our information, including without limitation, specifications, data sheets and application notes for semiconductor devices, as well as the precautions and conditions set forth in the "Semiconductor Reliability Handbook".
- 4.When designing electronics applications by referring to this Reference Design, customers must evaluate the whole system adequately. Customers are solely responsible for all aspects of their own product design or applications. WE ASSUME NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- 5.No responsibility is assumed by us for any infringement of patents or any other intellectual property rights of third parties that may result from the use of this Reference Design. No license to any intellectual property right is granted by this terms of use, whether express or implied, by estoppel or otherwise.
- 6.THIS REFERENCE DESIGN IS PROVIDED "AS IS". WE (a) ASSUME NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (b) DISCLAIM ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO THIS REFERENCE DESIGN, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.

3. Export Control

Customers shall not use or otherwise make available this Reference Design for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). This Reference Design may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of this Reference Design are strictly prohibited except in compliance with all applicable export laws and regulations.

4. Governing Laws

This terms of use shall be governed and construed by laws of Japan.

RESTRICTIONS ON PRODUCT USE

- Toshiba Electronic Devices & Storage Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. **TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.**
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Product may include products using GaAs (Gallium Arsenide). GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. **TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.**

TOSHIBA

* Arm and Cortex are registered trademarks of Arm Limited (or its subsidiaries) in the US and/or elsewhere.

* TXZ+TM is a trademark of Toshiba Electronic Devices & Storage Corporation.

* All other company names, product names, and service names may be trademarks of their respective companies.